

## Dual P-Channel 20 V (D-S) MOSFET

### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)	$Q_g$ (Typ.)
- 20	0.183 at $V_{GS} = - 4.5$ V	- 1.3 <sup>a</sup>	1.6 nC
	0.262 at $V_{GS} = - 2.5$ V	- 1.2	
	0.383 at $V_{GS} = - 1.8$ V	- 1.0	

### FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- PWM Optimized
- Compliant to RoHS Directive 2002/95/EC

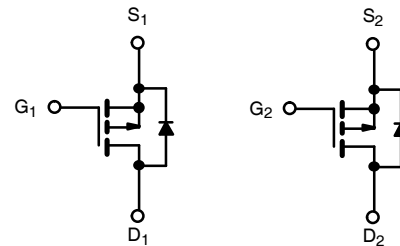
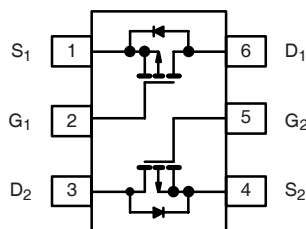


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**  
 Available

### APPLICATIONS

- Load Switch for Portable Devices

SOT-323-6



### ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	- 20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current ( $T_J = 150$ °C)	$I_D$	$T_C = 25$ °C - 1.3 <sup>a</sup>	A
		$T_C = 70$ °C - 1.1	
		$T_A = 25$ °C - 1.0 <sup>b, c</sup>	
		$T_A = 70$ °C - 0.83 <sup>b, c</sup>	
Pulsed Drain Current	$I_{DM}$	- 3	A
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25$ °C - 1	
		$T_A = 25$ °C - 0.6 <sup>b, c</sup>	
Maximum Power Dissipation	$P_D$	$T_C = 25$ °C 1.25	W
		$T_C = 70$ °C 0.8	
		$T_A = 25$ °C 0.74 <sup>b, c</sup>	
		$T_A = 70$ °C 0.47 <sup>b, c</sup>	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	°C

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>b, d</sup>	$R_{thJA}$	130	170	°C/W
Maximum Junction-to-Foot (Drain)	$R_{thJF}$	80	100	

Notes:

- Package limited.
- Surface mounted on 1" x 1" FR4 board.
- $t = 5$  s.
- Maximum under steady state conditions is 220 °C/W.

SPECIFICATIONS $T_J = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	- 20			V
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = -250\text{ }\mu\text{A}$		- 20		mV/ $^{\circ}\text{C}$
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			2		
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	- 0.3		- 1.3	V
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 8\text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}$			- 1	$\mu\text{A}$
		$V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}, T_J = 85\text{ }^{\circ}\text{C}$			- 10	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \leq -5\text{ V}, V_{GS} = -4.5\text{ V}$	- 3			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = -4.5\text{ V}, I_D = -0.91\text{ A}$		0.183	0.201	$\Omega$
		$V_{GS} = -2.5\text{ V}, I_D = -0.8\text{ A}$		0.262	0.288	
		$V_{GS} = -1.8\text{ V}, I_D = -0.25\text{ A}$		0.383	0.421	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = -10\text{ V}, I_D = -0.91\text{ A}$		2		S
Dynamic <sup>b</sup>						
Input Capacitance	$C_{iss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		237		pF
Output Capacitance	$C_{oss}$			26		
Reverse Transfer Capacitance	$C_{rss}$			16		
Total Gate Charge	$Q_g$	$V_{DS} = -10\text{ V}, V_{GS} = -8\text{ V}, I_D = -1.1\text{ A}$		2.6	4.0	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -10\text{ V}, V_{GS} = -4.5\text{ V}, I_D = -1.1\text{ A}$		1.6	2.4	
Gate-Drain Charge	$Q_{gd}$			0.36		
				0.33		
Gate Resistance	$R_g$	$f = 1\text{ MHz}$		7.5		$\Omega$
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10\text{ V}, R_L = 12\text{ }\Omega$ $I_D \cong -0.83\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 1\text{ }\Omega$		12	20	ns
Rise Time	$t_r$			27	40	
Turn-Off Delay Time	$t_{d(off)}$			15	25	
Fall Time	$t_f$			10	15	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10\text{ V}, R_L = 12\text{ }\Omega$ $I_D \cong -0.83\text{ A}, V_{GEN} = -8\text{ V}, R_g = 1\text{ }\Omega$		2	5	
Rise Time	$t_r$			12	20	
Turn-Off Delay Time	$t_{d(off)}$			12	20	
Fall Time	$t_f$			10	15	
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25\text{ }^{\circ}\text{C}$			- 1.0	A
Pulse Diode Forward Current <sup>a</sup>	$I_{SM}$				- 3.0	
Body Diode Voltage	$V_{SD}$	$I_S = -0.9\text{ A}$		- 0.8	- 1.2	V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = -0.83\text{ A}, dI/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^{\circ}\text{C}$		25	50	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			15	30	nC
Reverse Recovery Fall Time	$t_a$			12		ns
Reverse Recovery Rise Time	$t_b$			13		

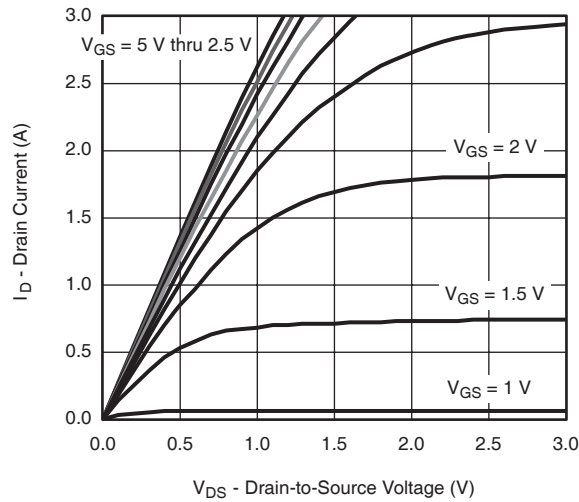
Notes:

 a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ 

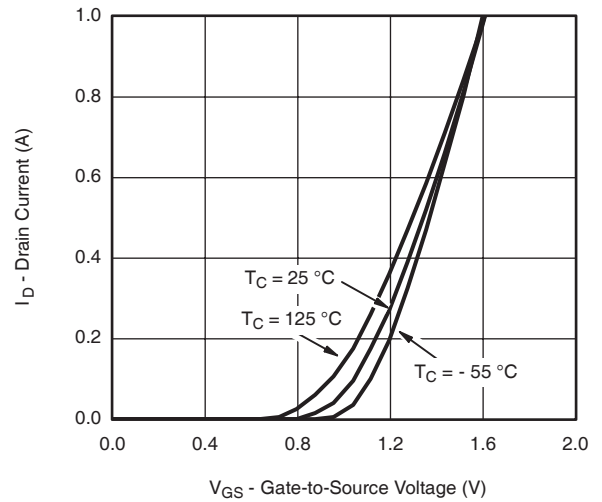
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

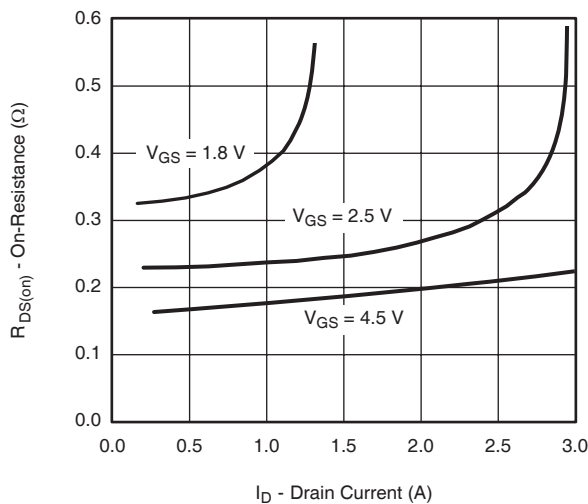
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



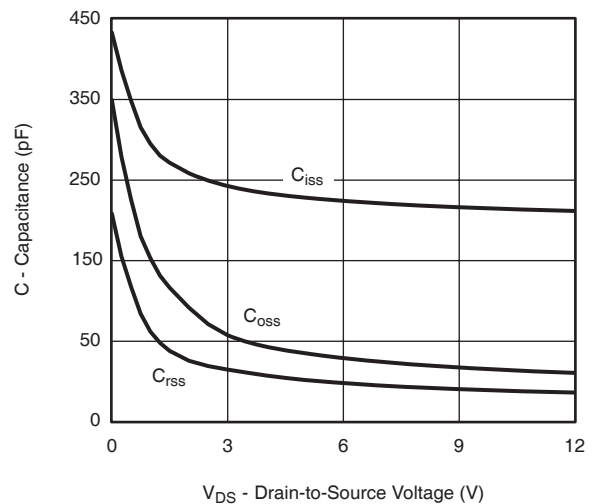
**Output Characteristics**



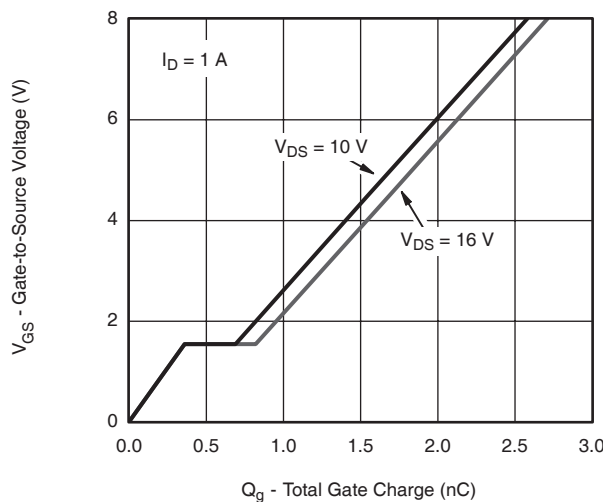
**Transfer Characteristics**



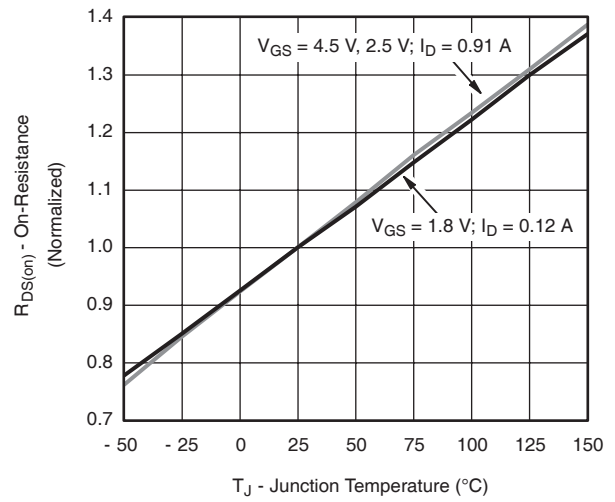
**On-Resistance vs. Drain Current and Gate Voltage**



**Capacitance**

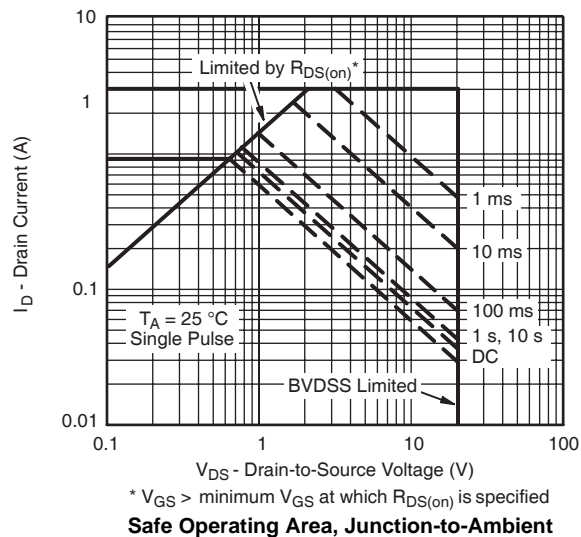
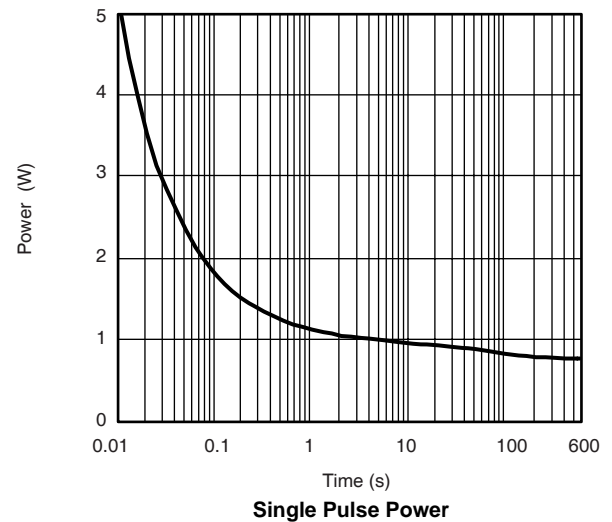
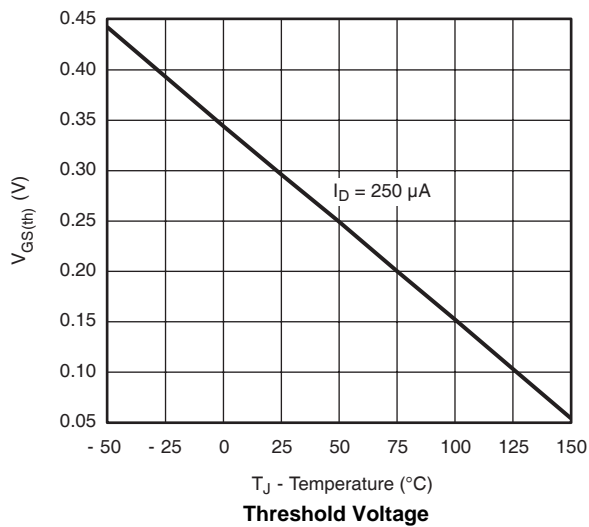
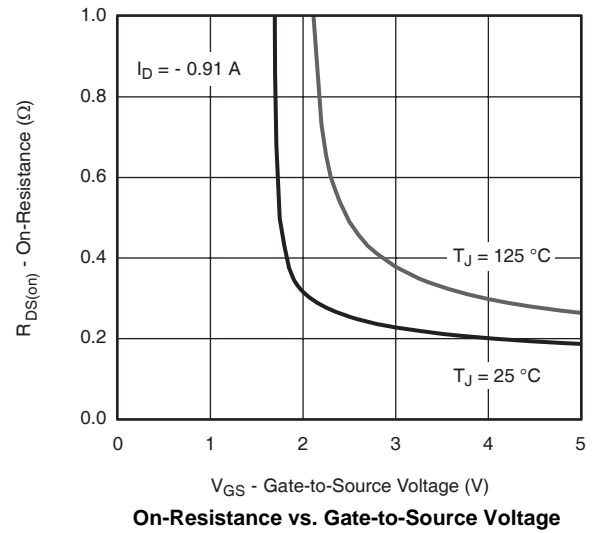
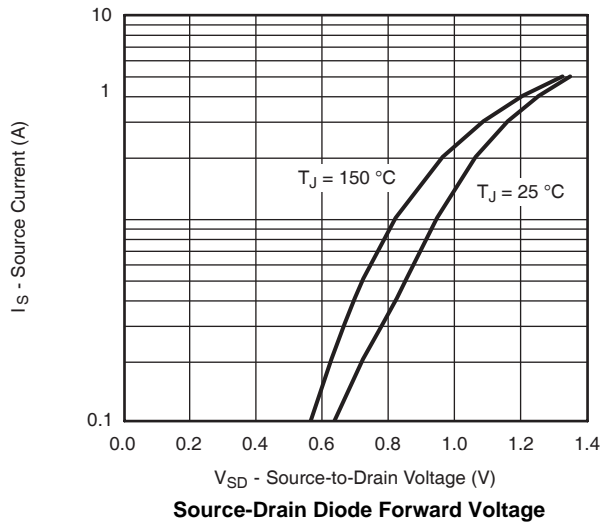


**Gate Charge**

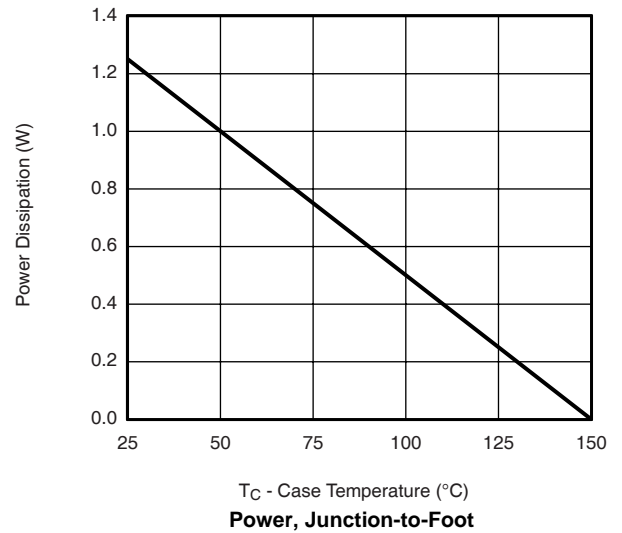
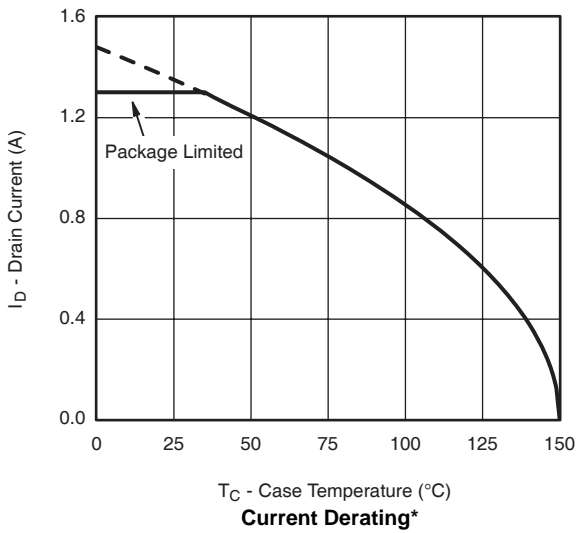


**On-Resistance vs. Junction Temperature**

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

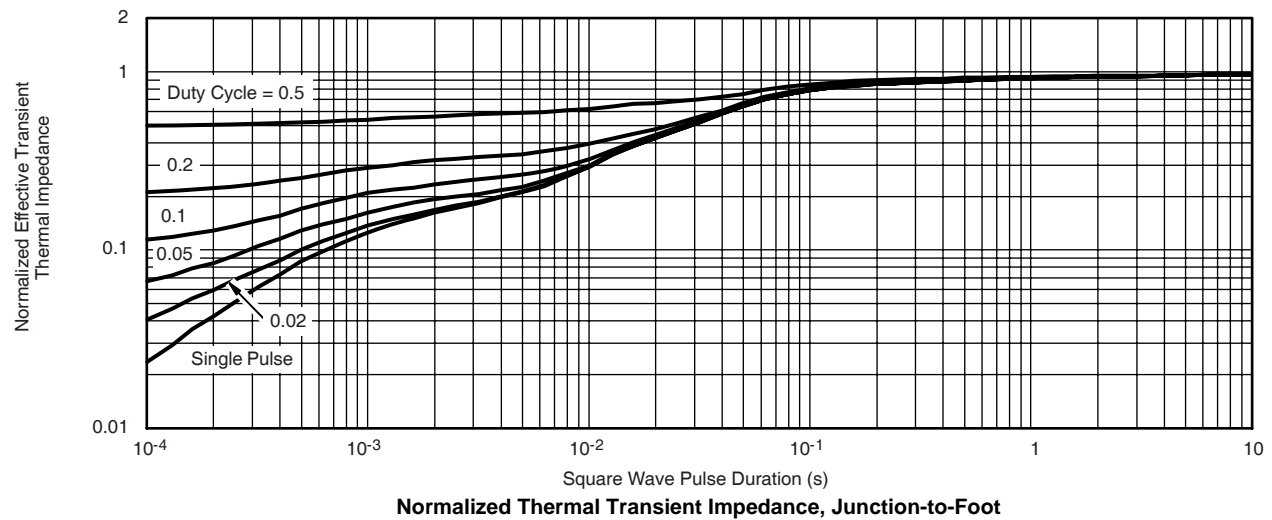
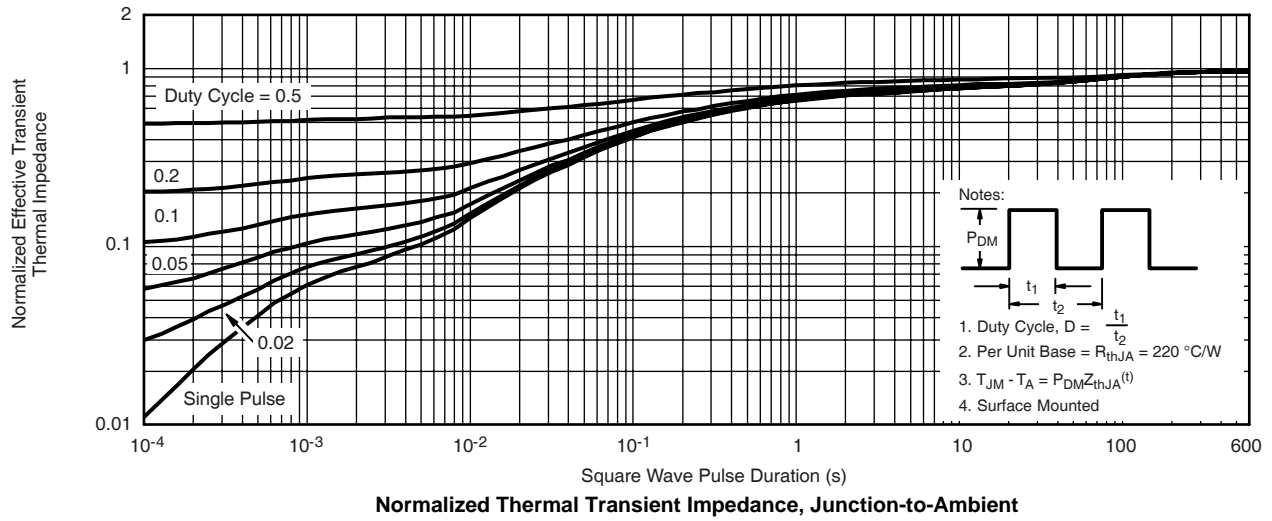


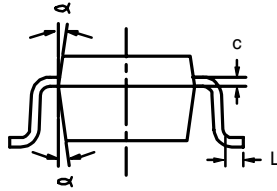
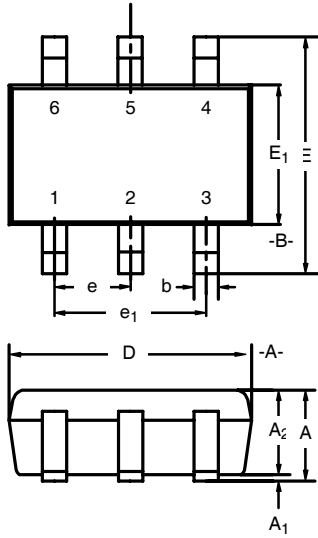
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

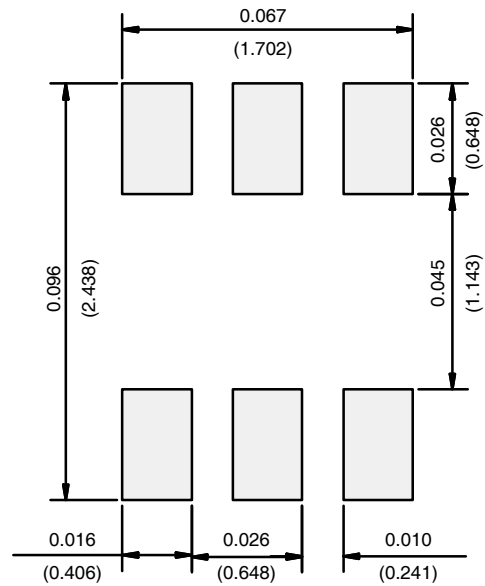
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted





Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
<b>A</b>	0.90	—	1.10	0.035	—	0.043
<b>A<sub>1</sub></b>	—	—	0.10	—	—	0.004
<b>A<sub>2</sub></b>	0.80	—	1.00	0.031	—	0.039
<b>b</b>	0.15	—	0.30	0.006	—	0.012
<b>c</b>	0.10	—	0.25	0.004	—	0.010
<b>D</b>	1.80	2.00	2.20	0.071	0.079	0.087
<b>E</b>	1.80	2.10	2.40	0.071	0.083	0.094
<b>E<sub>1</sub></b>	1.15	1.25	1.35	0.045	0.049	0.053
<b>e</b>	0.65BSC			0.026BSC		
<b>e<sub>1</sub></b>	1.20	1.30	1.40	0.047	0.051	0.055
<b>L</b>	0.10	0.20	0.30	0.004	0.008	0.012
<b>α</b>	7°Nom			7°Nom		

**RECOMMENDED MINIMUM PADS FOR SOT323: 6-Lead**



Recommended Minimum Pads  
Dimensions in Inches/(mm)



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